



Bipolar PNP Bare Die – BTP6982

Part Description

The BTP6982 is a silicon BJT transistor available in bare die form and well suited for use in general purpose switching and amplifier applications.

Key Parameters:

- VCBO = -180V
- VCEO = -140V
- VEBO = -7V
- hFE = 100-300 @ VCE = -5V, IC = -1A
- VCE(Sat) = -0.37V @ IC = -3A, IB = -300mA
- fT = 120 MHz @ VCE = -10V, IE = 0A
- COBO = 33pF @ VCB = -10V

Features

Very Low VCE(sat). Designed to provide performance equivalent to ZETEX / DIODES INC. ZX5T955G

Die Size (Unawn)

1240µm X 1240µm, 49 Mils X 49 Mils

This is a shortform datasheet only

For the full datasheet

Please contact sales@siliconsupplies.com

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